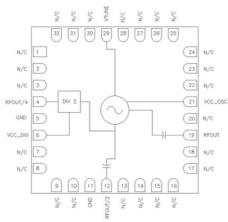


# **RFVC1831**

# 7.3GHz to 8.2GHz MMIC VCO with Fo/2 and Fo/4 Outputs

RFMD's RFVC1831 is a 5V InGaP MMIC VCO with an integrated frequency divider providing additional Fo/2 and Fo/4 outputs. With an Fo frequency range of 7.3GHz to 8.2GHz its monolithic structure provides excellent temperature, shock, and vibration performance. Output power (Fo) is +10dBm and is flat across the tuning voltage range of 1.5V to 14.5V. Phase noise is typically -115dBc/Hz at 100kHz offset. The device operates from a low supply current of 230mA which can be further reduced to 170mA by disabling the divider functions if not required. The RFVC1831 is available in a low cost 5mm x 5mm surface mount plastic overmolded QFN outline.



Functional Block Diagram

### **Ordering Information**

RFVC1831S2	Sample bag with 2 pieces		
RFVC1831SB	Sample bag with 5 pieces		
RFVC1831SQ	Bag with 25 pieces		
RFVC1831SR	Bag with 100 pieces		
RFVC1831TR7	7" Reel with 750 pieces		
RFVC1831PCBA-410	Evaluation Board		



Package: Plastic QFN, 32-pin, 5mm x 5mm x 0.85mm

#### **Features**

- Multiple Frequency Outputs
  - Fo: 7.30GHz to 8.20GHz
  - Fo/2: 3.65GHz to 4.10GHz
  - Fo/4: 1.83GHz to 2.05GHz
- No External Resonator Required
- Integrated Frequency Divider
- Phase Noise: -115dBc/Hz at 100kHz Offset
- Flat Output Power Over Frequency Tuning Range 1.5V to 14.5V
  - Fo: 10dBm
  - Fo/2: 4dBm
  - Fo/4: -2dBm
- Low Power Consumption
  - 5V/230mA (Divider On)
  - 5V/170mA (Divider Off)
- 32-Lead 5mm x 5mm Plastic Overmolded QFN

#### **Applications**

- Point-to-Point Radio
- Point-to-Multipoint Radio
- Satellite Communications
- Test Equipment
- Military
- Aerospace



#### **Absolute Maximum Ratings**

Parameter	Rating	Unit
V <sub>CC_OSC</sub> , V <sub>CC_DIG</sub>	+5.5	V
V <sub>TUNE</sub>	0 to +15	V
Junction Temperature (T <sub>J</sub> )	135	°C
Continuous P <sub>DISS</sub> (T <sub>A</sub> = 85°C) (derate 37mW/°C above T <sub>A</sub> = 85°C)	1.65	W
Junction to Case, Thermal Resistance (R <sub>θ(j-a)</sub> )	30	°C/W
Storage Temperature	-65 to +150	°C
Operating Temperature	-40 to +85	°C
ESD Sensitivity (HBM)	Class 1A	



Caution! ESD sensitive device.



RFMD Green: RoHS status based on EU Directive 2011/65/EU (at time of this document revision), halogen free per IEC 61249-2-21, < 1000ppm each of antimony trioxide in polymeric materials and red phosphorus as a flame retardant, and <2% antimony in solder.

Exceeding any one or a combination of the Absolute Maximum Rating conditions may cause permanent damage to the device. Extended application of Absolute Maximum Rating conditions to the device may reduce device reliability. Specified typical performance or functional operation of the device under Absolute Maximum Rating conditions is not implied.

#### **Nominal Operating Parameters**

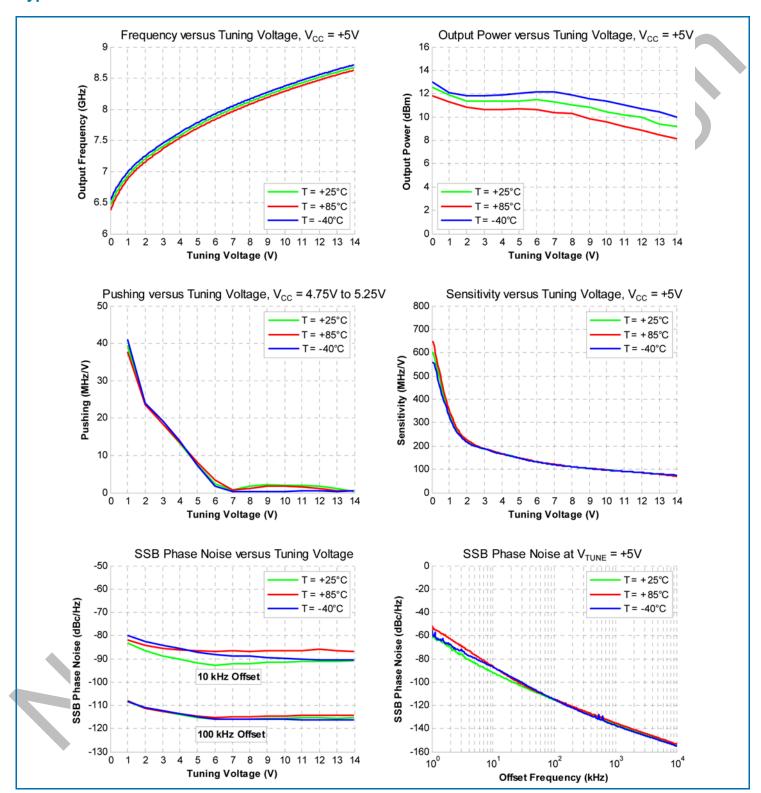
Parameter	Specification			Unit	Condition
rarameter	Min	Тур	Max	Unit	Condition
Electrical Specifications					V <sub>CC</sub> = 5V, T <sub>A</sub> = +25°C
Operating Frequency					
Fo	7.30		8.20	GHz	
Fo/2	3.65		4.10	GHz	
Fo/4	1.83		2.05	GHz	
Output Power					
Fo		10		dBm	
Fo/2		4		dBm	
Fo/4		-2		dBm	
SSB Phase Noise					
10 kHz offset at RF <sub>OUT</sub>		-91		dBc/Hz	V <sub>TUNE</sub> = 5V
100 kHz offset at RF <sub>оит</sub>		-115		dBc/Hz	
Tune Voltage	1.5		14.5	V	
Supply Voltage (Oscillator and Divider)		5		V	
Supply Current					
V <sub>cc_osc</sub>		170		mA	
V <sub>CC_DIG</sub>		60		mA	
Tune Port Leakage Current				μA	
Output Return Loss				dB	



Parameter	Specification		Unit	Condition		
Mi		Тур	Max	Onit	Condition	
Electrical Specifications (continued)						
Harmonics/Sub-harmonics					Measured with RF probes at package, not at SMA connections on EVB	
1/2		60		dBc		
3/2		50		dBc		
2 <sup>nd</sup>		15		dBc		
3 <sup>rd</sup>		25		dBc		
Pulling (into a 2.0:1 VSWR)		5		MHz pp		
Pushing		25		MHz/V		
Frequency Drift Rate		0.8		MHz/°C		

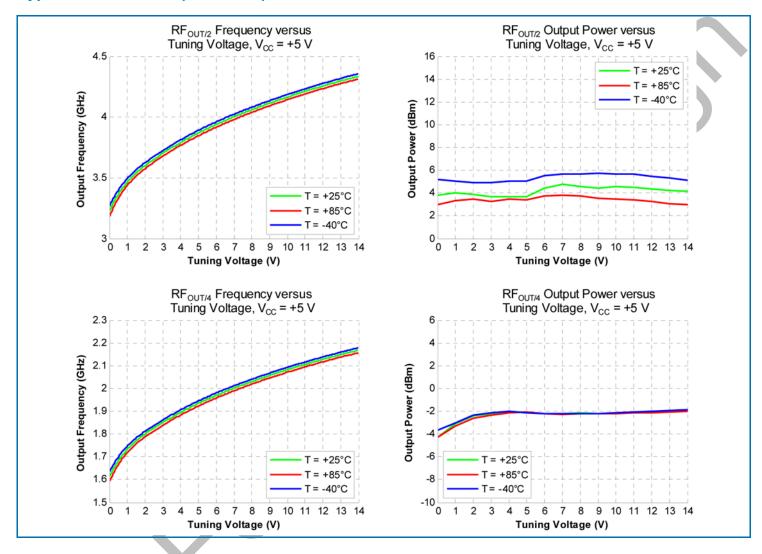


#### **Typical Performance**





#### **Typical Performance (continued)**





#### **Pin Names and Descriptions**

Pin	Name	Description	Interface Schematic
1-3	N/C	No internal connection.	
4	RFOUT/4	VCO RF output at Fo/4. Externally DC-blocked.	5 V RFOUT/4
5	GND	Connect to PCB ground.	GND =
6	VCC_DIG	Supply voltage input for the integrated frequency divider. Typical +5V. Ground this pin to disable digital divider and reduce current consumption by 60mA.	VCC_DIG
7-10	N/C	No internal connection.	
11	GND	Connect to PCB ground.	See Pin 5 interface schematic
12	RFOUT/2	VCO RF output at Fo/2. Internally DC-blocked.	RFOUT/2 •—
13-18	N/C	No internal connection.	
19	RFOUT	VCO RF output at Fo. Internally DC-blocked.	RFOUT 0
20	N/C	No internal connection.	
21	VCC_OSC	Supply voltage input for the VCO. Typical +5V.	vcc_osc



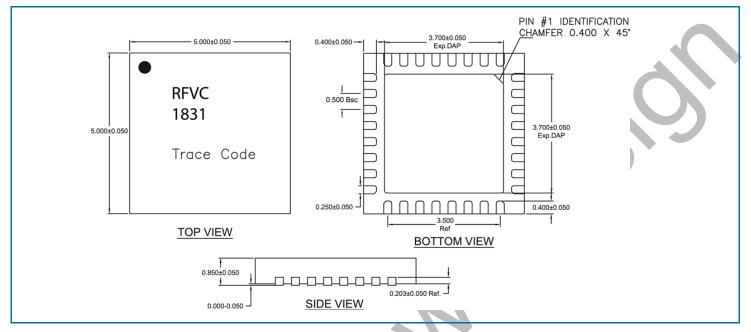
### **Pin Names and Descriptions (continued)**

Pin	Name	Description	Interface Schematic
22-28	N/C	No internal connection.	
29	VTUNE	VCO control voltage input.	VTUNE
30-32	N/C	No internal connection.	
PKG BASE	GND	Connect to PCB ground.	See Pin 5 interface schematic





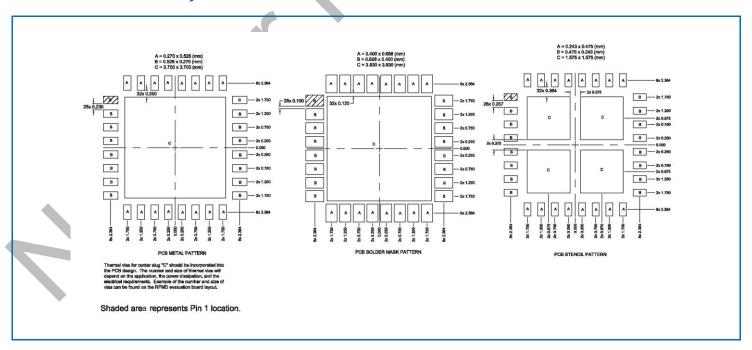
#### Package Drawing (all dimensions in mm)



#### Notes:

- 1. Dimensions are for reference only.
- 2. Package body material: Plastic.
- 3. Lead and paddle plating: 8µm minimum of Sn over Cu leadframe.

#### **Recommended PCB Layout**

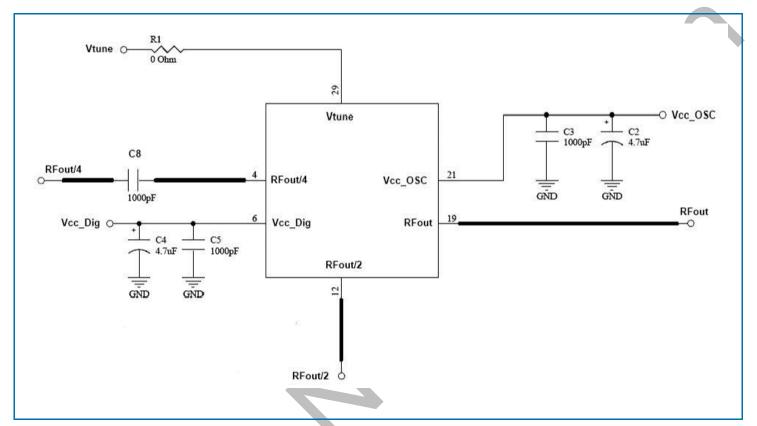


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# **Sample Application Circuit Schematic**

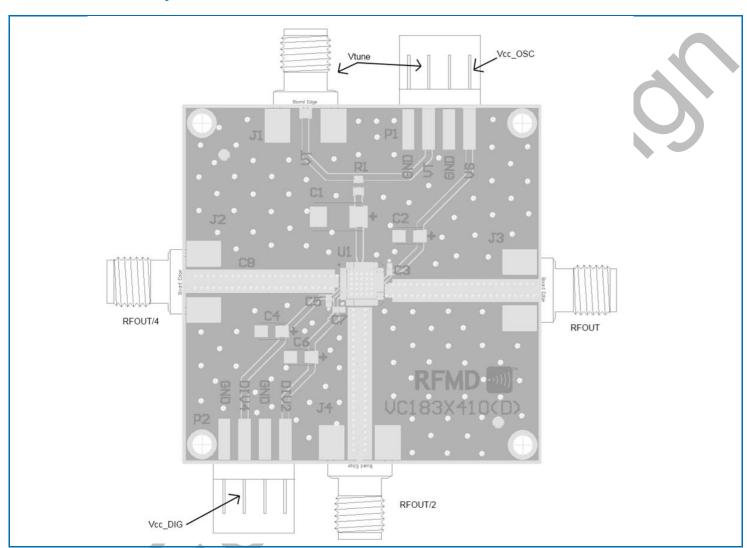


Bias Conditions	Output
$V_{CC_OSC} = 5V$	F <sub>OUT</sub> = 7.7GHz
V <sub>CC_DIG</sub> = 5V	F <sub>OUT/2</sub> = 3.85GHz
$V_{TUNE} = 5V$	F <sub>OUT/4</sub> = 1.975GHz

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## **Evaluation Board Layout**



# **Evaluation Board Bill of Materials (BOM)**

Item	Description
U1	RFVC1831 VCO
C3, C5, C7, C8	1000pF Capacitor, 0402 Package
C2, C4, C6	4.7μF Tantalum Capacitor
C1	68µF Tantalum Capacitor
R1	0Ω Resistor, 0603 Package
P1, P2	4-PIN DC connector
J1, J2, J3, J4	PCB mount SMA connector
PCB	VC183x410(D)